## Process-Structure-Properties Simulations for Predicting Fatigue Indicator Parameters of Additive Manufactured Ti-6Al-4V with Quantified Uncertainty

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## Outline

- Motivation and objectives
- Process-structure: Physically-based Monte Carlo
  - Thermal model and solidification
  - Example microstructures
- Structure-properties: Crystal plasticity
  - Model formulation
  - Micromechanical fields and fatigue indicator parameters
- Fatigue indicator parameter distributions and uncertainty quantification
- Concluding remarks

## Motivation

- Challenge using laser powder bed fusion additive manufacturing (AM) for flight hardware (Ti-6Al-4V): need to ensure acceptable fatigue performance
  - Influenced by build conditions, defects, microstructure, texture, etc.
- Process-structure-properties (PSP) simulations: understand how the design space maps to quantities of interest relevant for fatigue
- Need uncertainty quantification (UQ), verification, and validation to build confidence in AM processes and models<sup>1</sup>
  - Requires enough simulations or experiments to build up statistics on a quantity of interest

<sup>1</sup>S. Mahadevan et al., ASCE-ASME J Risk and Uncert in Engrg Sys Part B Mech Engrg. 8 (2022) 010801. <u>https://doi.org/10.1115/1.4053184</u>.



- Build a PSP framework capable of simulating many AM-generated microstructures
- Predict distributions of fatigue indicator parameters in the simulated microstructures
- Understand the influence of microstructural randomness, process parameters, and build defects (porosity) on the fatigue indicator parameters

## Process-structure: Physically-based Monte Carlo

- Stochastic Parallel Particle Kinetic
   Simulator (SPPARKS)<sup>1</sup>
  - Kinetic Monte Carlo framework from Sandia National Laboratories <u>https://spparks.github.io/</u>
  - Initially used for microstructural evolution (e.g., annealing, recrystallization)
- Application to AM: Physically-based Monte Carlo (PBMC)<sup>2,3</sup>
  - Thermal model → temperature field → melt pool

<sup>1</sup>This is not an endorsement by the National Aeronautics and Space Administration (NASA)
<sup>2</sup>T.M. Rodgers et al., Addit Manuf. 41 (2021) 101953. <u>https://doi.org/10.1016/j.addma.2021.101953</u>.
<sup>3</sup>J.G. Pauza et al., Modelling Simul Mater Sci Eng. 29 (2021) 055019. https://doi.org/10.1088/1361-651X/ac03a6. Melt pool from analytical thermal model (Rosenthal equation)





Background temperature

Melting temperature

$$T = T_0 + \frac{Q}{2\pi rk} \exp\left(-\frac{v(\xi + r)}{2\alpha}\right)$$

T: temperature T<sub>0</sub>: background temperature Q: absorbed power

v: scan speed

*r*: distance from point source

- $\xi$ : local scan direction coordinate
- ower k: thermal conductivity  $\alpha$ : thermal diffusivity

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- Application to AM: Physically-based Monte Carlo (PBMC)<sup>2,3</sup>
  - Thermal model  $\rightarrow$  temperature field  $\rightarrow$ melt pool
  - Solidification  $\rightarrow$  epitaxial grain growth, columnar grains

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Melt pool from analytical thermal model (Rosenthal equation)



Scan strategy (schematic)



Example microstructure



Ti-6Al-4V build parameters from O. Zinovieva et al., 141 (2018) 207–220. https://doi.org/10.1016/j.commatsci.2017.09.018.

## Process-structure: Physically-based Monte Carlo



## Microstructures: Equivalent ellipsoids

Aspect ratios for equivalent ellipsoids support observed dominance of columnar grains



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Aspect ratios for all grains across 200 simulations



## Structure-properties: Crystal plasticity

- Elasto-Viscoplastic Fast Fourier Transform (EVP-FFT)<sup>1</sup>
- Advantages
  - Speed improvements over crystal plasticity finite element methods
  - Shares voxel-based microstructure representation with SPPARKS (no need for meshing)

Flow rule: 
$$\dot{\boldsymbol{\varepsilon}}^p = \dot{\gamma}_0 \sum_{s=1}^{N_s} \boldsymbol{m}^s \left(\frac{|\boldsymbol{m}^s:\boldsymbol{\sigma}|}{\tau^s}\right)^n \operatorname{sgn}(\boldsymbol{m}^s:\boldsymbol{\sigma})$$

Voce hardening:

$$\tau^{s} = \tau_{0} + (\tau_{1} + \theta_{1}\Gamma) \left[ 1 - \exp\left(-\frac{\theta_{0}}{\tau_{1}}\Gamma\right) \right]$$
$$\Gamma = \sum_{s=1}^{N_{s}} \int \dot{\gamma}^{s} dt$$

Implicit time discretization:  $\boldsymbol{\sigma} = \mathbf{C} : \left(\boldsymbol{\varepsilon}_{t+\Delta t} - \boldsymbol{\varepsilon}_{t}^{p} - \dot{\boldsymbol{\varepsilon}}_{t+\Delta t}^{p} \Delta t\right)$ 

 $\dot{\gamma}_0$ : reference strain rate *n*: viscoplastic exponent  $\dot{\boldsymbol{\varepsilon}}^p$ : plastic strain rate tensor  $\boldsymbol{\sigma}$ : stress tensor *m<sup>s</sup>*: Schmid tensor for slip system *s*  $\tau^s$ : critical resolved shear stress for slip system s  $\dot{\gamma}^{s}$ : plastic shear strain on slip system s  $\tau_0, \tau_1, \theta_0, \theta_1$ : Voce hardening law parameters  $\Gamma$ : accumulated slip on all slip systems t,  $\Delta t$ : time, time step **C**: stiffness tensor *ε*: total strain tensor  $\varepsilon^p$ : plastic strain tensor

<sup>1</sup>R.A. Lebensohn et al., Int J Plast. 32–33 (2012) 59–69. <u>https://doi.org/10.1016/j.ijplas.2011.12.005</u>. This is not an endorsement by NASA.

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 $\frac{One \ of \ 12 \ possible \ \alpha \ variants}{randomly \ selected \ for \ each \ grain}$ 



0.6% applied strain in build direction; periodic boundary conditions on sides of domain



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parameters (FIPs) • Here: equivalent plastic strain  $\varepsilon^p = \int \dot{\varepsilon}^p dt \qquad \dot{\varepsilon}^p = \sqrt{\frac{2}{3}} \dot{\varepsilon}^p : \dot{\varepsilon}^p$ 

Goal: distributions of fatigue indicator

Micromechanical fields

- Value assigned to each grain by volume averaging near hotspots
- Other possibilities: crystallographic parameters (e.g., slip-system-based Fatemi-Socie<sup>1</sup>)



# Summary of PSP framework Multiple simulations $\rightarrow$ probability distributions of FIPs and UQ Micromechanical fields from **Microstructures from PBMC** Analytical thermal model crystal plasticity Melting Background

temperature

temperature

## FIP distributions: No porosity

- 200 simulations with full PSP framework, no pores
- Fatigue is an extreme value phenomenon → consider upper tail of the distribution
- How does the distribution shift in the presence of pores?

Equivalent plastic strain for all grains across 200 simulations

Example microstructure

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## FIP distributions: Porosity vs. no porosity

• 200 simulations with average of one 30-µm keyhole pore per simulation

Example microstructure with a keyhole pore



## FIP distributions: Porosity vs. no porosity

- 200 simulations with average of one 30-µm keyhole pore per simulation
- Overall distribution of plastic strain is similar



## FIP distributions: Porosity vs. no porosity

- 200 simulations with average of one 30-µm keyhole pore per simulation
- Overall distribution of plastic strain is similar
- But extreme values are shifted!



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Equivalent plastic strain for all grains across 200 simulations, log scale

## FIP: Extreme values, no porosity

- 99<sup>th</sup> percentile of equivalent plastic strain  $\rightarrow$  extreme values of the FIP
- Uncertainty bounds (confidence interval) based on binomial distribution<sup>1</sup>



<sup>&</sup>lt;sup>1</sup>A.B. Owen, *Monte Carlo Theory, Methods, and Examples*. 2013.

## FIP: Extreme values, porosity vs. no porosity

### 99<sup>th</sup> percentile for simulations with pores

- Stable lower bound but upper bound of 95% confidence interval fluctuates
- Points toward pore-microstructure interactions

Sample-based estimate of equivalent plastic strain 99<sup>th</sup> percentile across all grains without and with porosity



## Concluding remarks

- PSP framework can simulate many builds and determine distributions of quantities of interest relevant to fatigue (FIPs)
- We can quantify the influence of pores on the extreme values of FIP distributions
  - Small, isolated pores: minimal influence on overall distribution
  - Small pores + interaction with local microstructure  $\rightarrow$  heavy tail of FIP distribution
- Ongoing work
  - Enhancements to each step in the framework (e.g., grain nucleation, columnar-equiaxed transition, α variant selection, FIP determination)
  - More advanced UQ (e.g., sensitivity analysis, multi-fidelity Monte Carlo, extreme value distributions)

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99<sup>th</sup> percentile of equivalent plastic strain across 200 simulations